NSN 5961-00-722-1266

Demilitarization:

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-722-1266 **Inclosure Material:** Metal **Overall Length:** Between 0.215 inches and 0.320 inches Overall Diameter: Between 0.320 inches and 0.360 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 4.0 breakdown voltage, emitter-to-base, collector open and 60.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 2.50 amperes source cutoff current **Power Rating Per Characteristic:** 18.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**